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Vishay Siliconix

## Low Voltage, Dual DPDT in miniQFN16

### DESCRIPTION

The DG2599 is a CMOS Dual DPDT (Dual Double Pole Double Throw) analog switch that operates over a wide voltage range of 1.65 V to 5 V. It is optimized for portable applications switching audio, SIM card signals, and other low power signals.

The DG2599 features low ON resistance of 2.8 W at 3 V power supply, fast switching speed, and low power consumption even when control logic signals are below V+ power supply voltage. The well matched dual DPDT switches conduct signals equally in both directions. The DG2599 is designed to guarantee break before make switching.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG2599 are offered in a miniQFN package. The miniQFN package has a nickel palladium- gold device termination and is represented by the lead (Pb)-free "-E4" suffix. The nickel-palladium-gold device terminations meet all JEDEC<sup>®</sup> standards for reflow and MSL ratings.

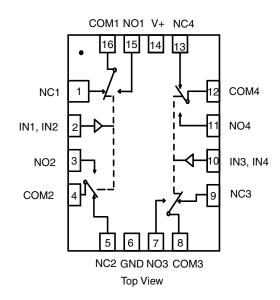
## FEATURES

- Halogen-free according to IEC 61249-2-21 definition
- Low voltage operation: 1.65 V to 5.5 V
- Low on-resistance: 2.8 W at V+ = 3 V
- Power off protection on COM1 and COM2 pins
- Latch up current great than 300 mA per JESD78
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

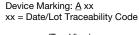
### APPLICATIONS

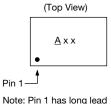
- Cellular phones
- PMPs and PDAs
- Modems and peripherals
- Computers and ebooks
- Tablet devices
- Displays and gaming
- STB

ORDERING INFORMATION					
PART NUMBER	PACKAGE				
DG2599DN-T1-GE4	miniQFN16 1.8 mm x 2.6 mm				



TRUTH TABLE (DG2599)						
LOGIC	LOGIC NC1, 2, 3 AND 4 NO 1, 2, 3 AND					
0	ON	OFF				
1	OFF	ON				







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<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ , unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Reference to GND	V+		-0.3 to +6	V	
Reference to GND	IN, COM, NC, NO <sup>a</sup>		-0.3 to (V+ + 0.3)	v	
Current (any terminal except NO, NC or COM)			30		
Continuous current (NO, NC, or COM)		± 300	mA		
Peak current (pulsed at 1 ms, 10 % duty cycle)			± 500		
Storage temperature (D suffix)			-65 to +150		
Package solder reflow conditions <sup>d</sup>	miniQFN16		250		
Power dissipation (packages) <sup>b</sup>	miniQFN16 <sup>c</sup>		525	mW	

#### Note

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings

b. All leads welded or soldered to PC board

c. Derate 6.6 mW/°C above 70 °C

d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

ELECTRICAL CHARACTERISTICS (V+ = 3 V)								
PARAMETER	TEST CONDITIONS	TEMP.	MIN.	TYP.	MAX.	UNIT		
Power Supply and Signal								
V+ supply voltage		Full	1.65	-	5.5	V		
V+ supply current	V <sub>IN</sub> = 0 or V+	Full	-	0.001	2	μA		
Analog signal range		Full	0	-	V+	V		
Switch On-Resistance and Leaka	ge							
Drain-source on-resistance	V+ = 3 V, I <sub>NO/NC</sub> = 100 mA, V <sub>COM</sub> = 0.9 V, 2.3 V	Room	-	2.8	3.3			
Drain-source on-resistance	$V + = 5 V$ , $I_{NO/NC} = 100 \text{ IIIA}$ , $V_{COM} = 0.9 V$ , 2.3 V	Full	-	-	3.6	w		
On-resistance flatness	$V_{1} = 2V_{1} = -100 \text{ m} V_{1} = -0 \text{ to } V_{1}$	Room	-	0.24	1.1	- VV		
On-resistance namess	V+ = 3 V, $I_{NO/NC}$ = 100 mA, $V_{COM}$ = 0 to V+	Full	-	-	1.3			
Switch off leakage current	$V_{+} = 4.3 V, V_{NO/NC} = 0.3 V/4 V, V_{COM} = 4 V / 0.3 V$	Room	-10	0.1	10	nA		
Switch on leakage current	$v_{+} = 4.5 v, v_{NO/NC} = 0.5 v/4 v, v_{COM} = 4 v / 0.3 v$	Full	-100	-	100			
Channel on lookage ourrent		Room	-10	0.1	10			
Channel on-leakage current	V+ = 4.3 V, V <sub>NO/NC</sub> and V <sub>COM</sub> = 0.3 V / 4 V	Full	-100	-	100			
Digital Control								
Input, high voltage	V+ = 4.3 V	Full	1.6	-	-			
input, nigh voltage	V+ = 3 V		1.3	-	-	v		
	V+ = 4.3 V	Full	-	-	0.6	v		
Input, low voltage	V+ = 3 V		-	-	0.5			
Input, bias current	$V_{IN} = V+$	Full	-1	0.01	1	μA		
Dynamic Characteristics		•	•	•	•			
Turne and time a		Room	-	-	90			
Turn on-time	$V_{COM}$ or $V_{NO/NC}$ = 3 V, $R_L$ = 50 $\Omega,~C_L$ = 35 pF	Full	-	-	115	1		
Turn off-time	$V_{COM}$ or $V_{NO/NC}$ = 3 V, R <sub>L</sub> = 50 $\Omega$ , C <sub>L</sub> = 35 pF	Room	-	-	70			
	$v_{COM}$ or $v_{NO/NC} = 3 v$ , $R_L = 50 \Omega_2$ , $C_L = 35 pF$	Full	-	-	85	- ns		
		Room	2	-	-			
Break before make time	$V_{COM}$ or $V_{NO/NC}$ = 3 V, $R_L$ = 50 $\Omega$ , $C_L$ = 35 pF	Full	2	-	-			
Charge injection	$C_L = 1 \text{ nF}, R_{GEN} = 0 \Omega$	Room	-	± 10	-	рС		
Off isolation	$R_L = 50 \Omega$ , $C_L = 5 pF$ , f = 1 MHz		-	-66	-			
Crosstalk	$R_L = 50 \Omega$ , $C_L = 5 pF$ , f = 1 MHz, non-adjacent channels		-	-110	-	dB		
3 dB bandwith	$C_L = 5 \text{ pF}, R_L = 50 \Omega$		-	186	-	MHz		

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For technical questions, contact: <u>analogswitchtechsupport@vishay.com</u>

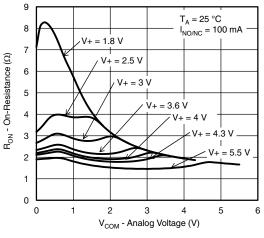
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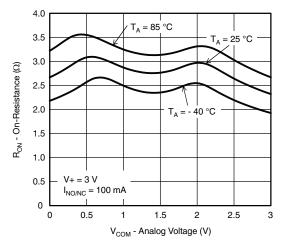
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ELECTRICAL CHARACTERISTICS ( $V + = 3 V$ )							
PARAMETER	TEST CONDITIONS	TEMP.	MIN.	TYP.	MAX.	UNIT	
Source off capacitance	$V_{IN} = 0$ or V+, f = 1 MHz		-	9	-	pF	
Channel on capacitance	$V_{IN} = 0$ or V+, f = 1 MHz		-	26	-	рг	

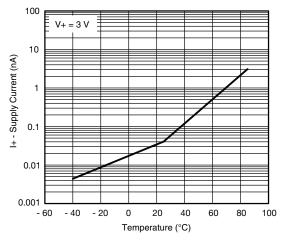
## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



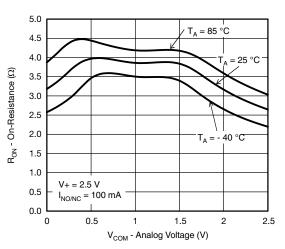
R<sub>ON</sub> vs. V<sub>COM</sub> and Single Supply Voltage



R<sub>ON</sub> vs. Analog Voltage and Temperature



Supply Current vs. Temperature

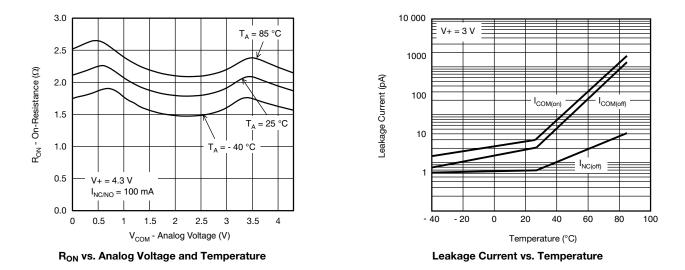


R<sub>ON</sub> vs. Analog Voltage and Temperature

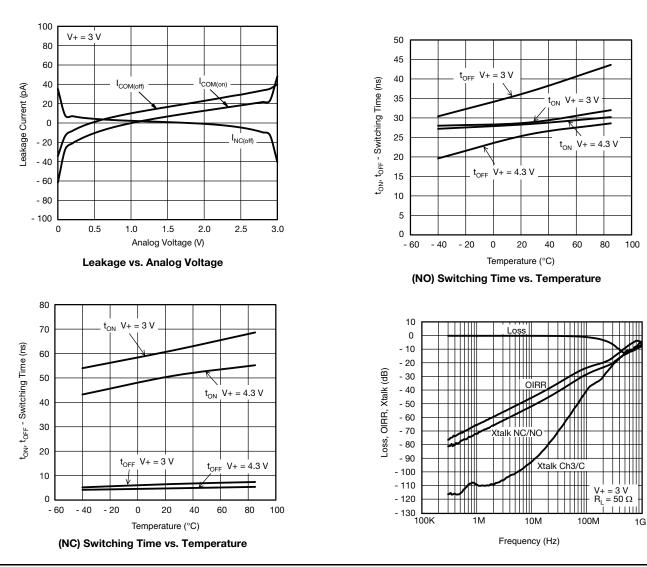
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## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



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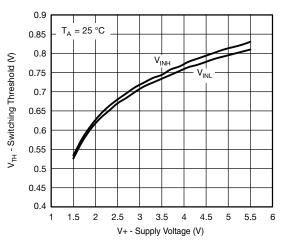
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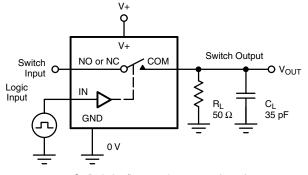


### Insertion Loss, Off Isolation and Crosstalk



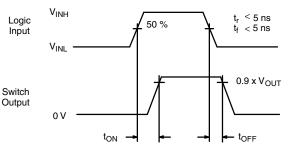
Switching Threshold vs. Supply Voltage

## **TEST CIRCUITS**



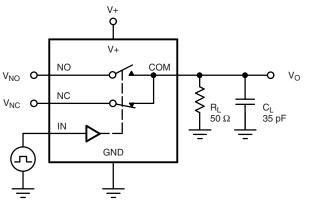
CL (includes fixture and stray capacitance)

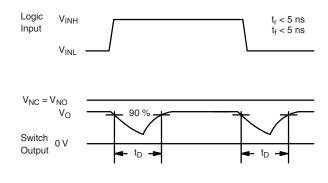
$$V_{OUT} = V_{COM} \left( \frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.







C<sub>L</sub> (includes fixture and stray capacitance)

#### Break-Before-Make Interval

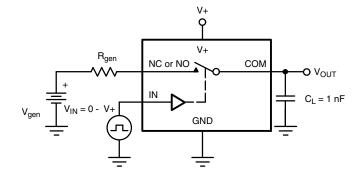
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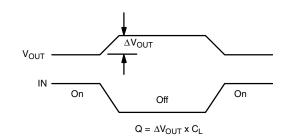
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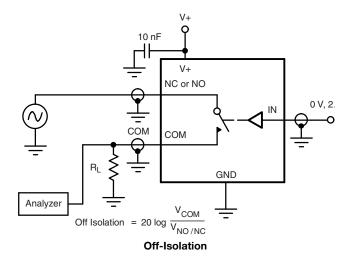
IN depends on switch configuration: input polarity determined by sense of switch.

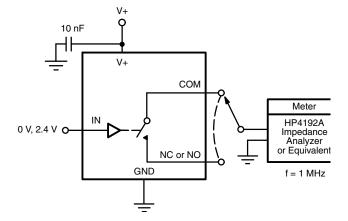
**Charge Injection** 



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## **TEST CIRCUITS**





Channel Off / On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?67667">www.vishay.com/ppg?67667</a>.

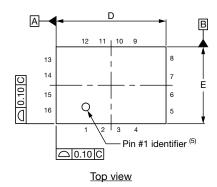
S21-0507-Rev. D, 24-May-2021

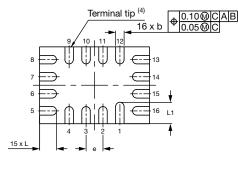
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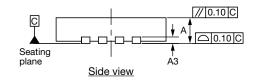
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# Thin miniQFN16 Case Outline





Bottom view



DIMENSIONS	MILLIMETERS <sup>(1)</sup>			INCHES			
DIMENSIONS	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	0.50	0.55	0.60	0.020	0.022	0.024	
A1	0	-	0.05	0	-	0.002	
A3	0.15 ref.				0.006 ref.		
b	0.15	0.20	0.25	0.006	0.008	0.010	
D	2.50	2.60	2.70	0.098	0.102	0.106	
е	0.40 BSC			0.016 BSC			
E	1.70	1.80	1.90	0.067	0.071	0.075	
L	0.35	0.40	0.45	0.014	0.016	0.018	
L1	0.45	0.50	0.55	0.018	0.020	0.022	
N <sup>(3)</sup>	16			16			
Nd <sup>(3)</sup>		4			4		
Ne <sup>(3)</sup>		4			4		

#### Notes

<sup>(1)</sup> Use millimeters as the primary measurement.

- <sup>(2)</sup> Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- <sup>(3)</sup> N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.

 $^{(4)}$  Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.

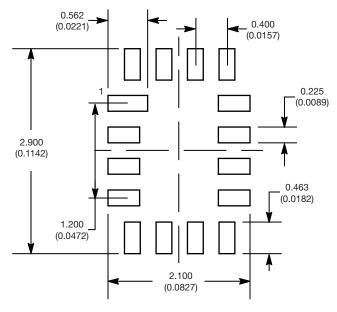
<sup>(5)</sup> The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.

<sup>(6)</sup> Package warpage max. 0.05 mm.

ECN: T16-0226-Rev. B, 09-May-16 DWG: 6023



## **RECOMMENDED MINIMUM PADS FOR MINI QFN 16L**



Mounting Footprint Dimensions in mm (inch)



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